## NSN 5961-01-043-4773

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Inclosure Material:	
Metal	
Overall Length:	
Between 0.240 inches and 0.260 inches	
Terminal Length:	
1.500 inches	
Overall Diameter:	
Between 0.335 inches and 0.370 inches	
Internal Configuration:	
Junction contact	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
140.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base	open and 7.0
breakdown voltage, emitter-to-base, collector open	
Current Rating Per Characteristic:	
Between 2.00 amperes source cutoff current and 10.00 amperes source cutoff current	
Power Rating Per Characteristic:	
15.0 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: npn	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
-	
Demilitarization:	
No	
Fiig:	
A110a0	